TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

2SA1873

Audio Frequency General Purpose Amplifier Applications

Unit: mm

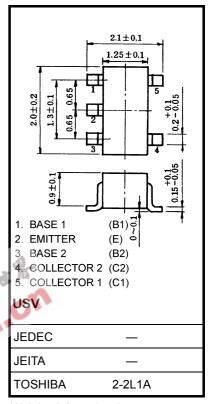
- Small package (dual type)
- High voltage and high current: $V_{CEO} = -50 \text{ V}$, $I_C = -150 \text{ mA}$ (max)
- High hFE
- Excellent hFE linearity: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)
- Complementary to 2SC4944

Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|----------------------------|------------------|------|
| Collector-base voltage | V_{CBO} | -50 | V |
| Collector-emitter voltage | V_{CEO} | -50 | V |
| Emitter-base voltage | V_{EBO} | -5 | V |
| Collector current | IC | –150 | mA |
| Base current | lΒ | -30 | mA |
| Collector power dissipation | P _C (Note 1) | 200 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | −5 5~12 5 | °C |

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

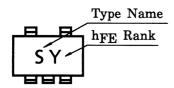


Weight: 6.2 mg (typ.)

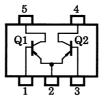
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

Marking



Equivalent Circuit (top view)



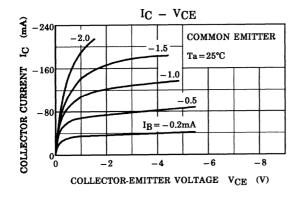
Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

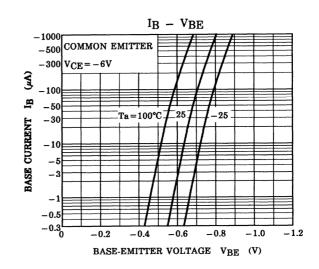
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|---------------------------|--|-----|------|------|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = -50 \text{ V}, I_E = 0$ | _ | _ | -0.1 | μΑ |
| Emitter cut-off current | I _{EBO} | $V_{EB} = -5 \text{ V}, I_C = 0$ | - | _ | -0.1 | μΑ |
| DC current gain | h _{FE} (Note) | $V_{CE} = -6 \text{ V}, I_C = -2 \text{ mA}$ | 120 | _ | 400 | |
| Collector-emitter saturation voltage | V _{CE (sat)} | $I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$ | | -0.1 | -0.3 | ٧ |
| Transition frequency | f _T | $V_{CE} = -10 \text{ V}, I_{C} = -1 \text{ mA}$ | 80 | _ | | MHz |
| Collector output capacitance | C _{ob} | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$ | _ | 4 | 7 | pF |

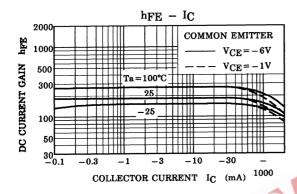
Note 2: hFE classification Y (Y): 120~240, GR (G): 200~400

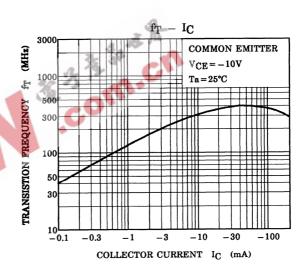
() marking symbol

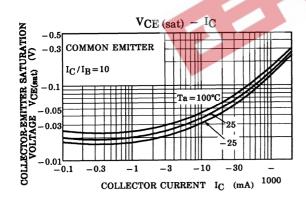
(Q1, Q2 common)

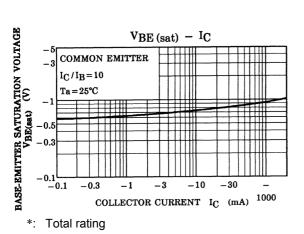


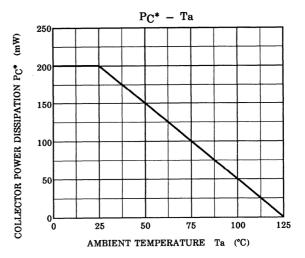












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20070701-EN GENERAL

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